

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,960,513 B2
APPLICATION NO. : 09/770699
DATED : November 1, 2005
INVENTOR(S) : Gealy

Page 1 of 2

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the title page item (56), under U.S. Pat. Documents

Page 2, col. 1, line 1, delete “Fukuxumi” and replace therewith --Fukuzumi--.

Column 6, line 9, delete “in” and replace therewith --is--.

Column 6, line 48, delete “including” and replace therewith --comprising--.

Column 6, line 51, delete “to first” and replace therewith --to a first--.

Column 7, line 29, delete “formed” and replace therewith --forming--.

Column 7, line 35-36, delete “a substrate” and replace therewith --the substrate assembly--.

Column 7, line 44, delete “of the hemispherical” and replace therewith --of hemispherical--.

Column 7, line 46, delete “forming the” and replace therewith --forming a--.

Column 7, lines 46-47, delete “hemispherical grain” and replace therewith --hemispherical grain polysilicon--.

Column 8, line 19, delete “a” and replace therewith --the--.

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It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 8, line 30, delete "hemispherical grain" and replace therewith --hemispherical grain polysilicon--.

Column 8, line 35, delete "extend" and replace therewith --extends--.

Signed and Sealed this

Fourth Day of March, 2008



JON W. DUDAS
Director of the United States Patent and Trademark Office